

M81016P/FP/KP

OCTAL D-TYPE FLIP-FLOP DRIVER WITH CLEAR

DESCRIPTION

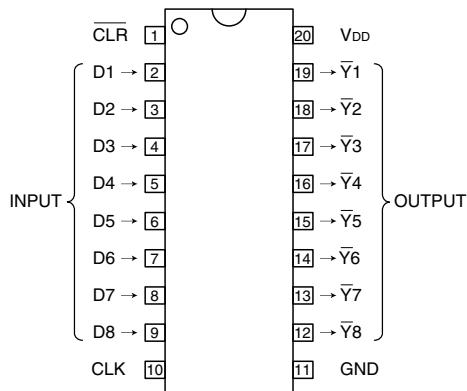
M81016 is octal D-type flip-flop driver by 20-pin package. It has 8 same circuit units which is composed of D-type flip-flop logic circuit and high voltage NchMOS output transistor. M81016 has a common direct clear input and a common clock input.

FEATURES

- Lineup with three packages
- High breakdown voltage ($BV_{DSX} \geq 40V$)
- Drain output current ($I_{DS(max)} = 200mA$)
- With input protection diodes
- Pin assignment of input-output flow through
- Wide operating temperature range ($T_a = -40$ to $+85^{\circ}C$)

APPLICATION

LED drive

PIN CONFIGURATION (TOP VIEW)

Package type
20P4B(P)
20P2N-A(FP)
20P2E-A(KP)

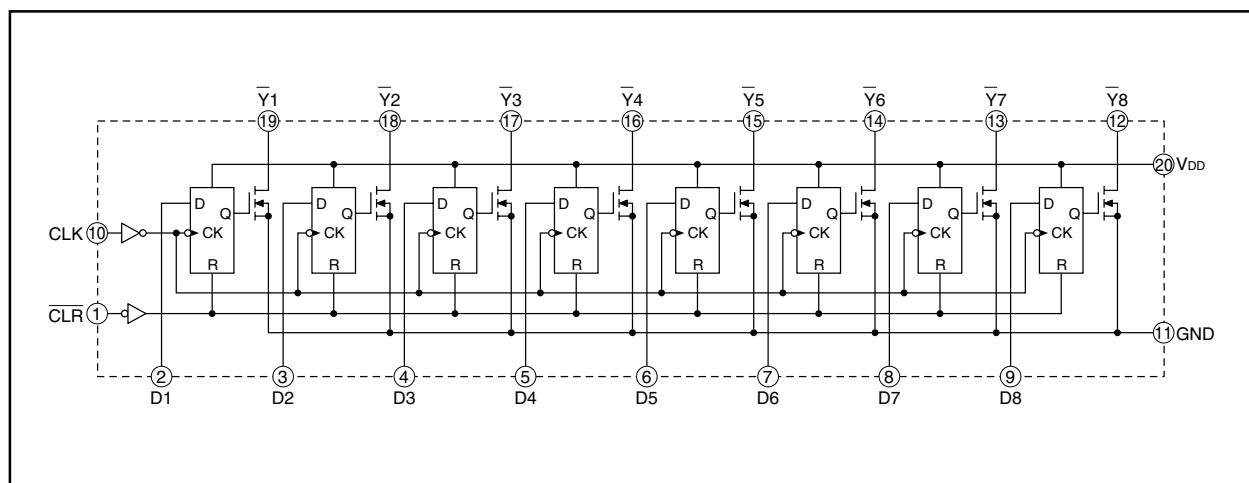
FUNCTION

The common direct clear input and common clock input are connected to every circuit unit by the same way. Signal at the D inputs is transferred to Y outputs by D-type flip-flops on the positive-going edge of the clock pulse.

If \overline{CLR} is set to "L", outputs \overline{Y}_1 - \overline{Y}_8 will be altogether set to "H" regardless of D1-D8 and CLK.

The maximum drain current of an output is 200mA. The maximum between drain-source is 40V.

Moreover, M81016FP/KP can save space with mini-flat package.

LOGIC DIAGRAM (POSITIVE LOGIC)

Oct.2004

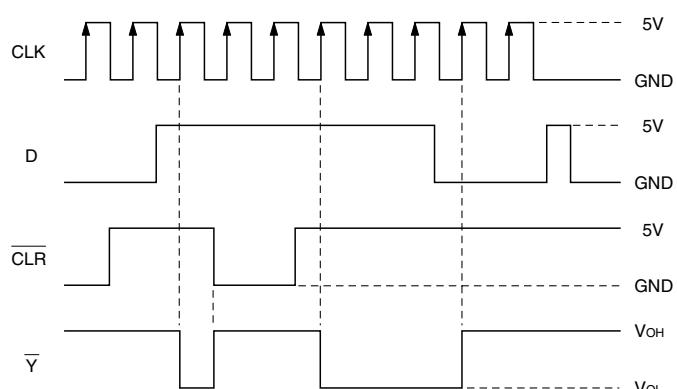
FUNCTION TABLE (EACH CHANNEL)

INPUT			OUTPUT : \bar{Y}
CLR	CLK	D	
L	X	X	H
H	↑	L	H
H	↑	H	L
H	L	X	Latched
H	↓	X	Latched

H : High level

L : Low level

X : Irrelevant

TIMING DIAGRAM**ABSOLUTE MAXIMUM RATINGS** (Unless otherwise noted, $T_a = -40 \sim +85^\circ\text{C}$)

Symbol	Parameter	Conditions	Ratings	Unit
VDD	Supply voltage		7	V
VDS	Drain-to-source voltage	Output, H	-0.5 ~ +40	V
VI	Input voltage		-0.5 ~ VDD	V
IDS	Drain output current	Current per circuit output, L	200	mA
Pd	Power dissipation	Ta = 25°C, when mounted on board	M81016P M81016FP M81016KP	1.47 1.10 0.68
T _{op}	Operating temperature		-40 ~ +85	°C
T _{stg}	Storage temperature		-55 ~ +125	°C

RECOMMENDED OPERATING CONDITIONS (Unless otherwise noted, $T_a = -40 \sim +85^\circ\text{C}$)

Symbol	Parameter	Conditions	Limits			Unit
			min	typ	max	
VDD	Supply voltage		4.5	5.0	5.5	V
VDS	Drain-to-source voltage		0	—	40	V
VIH	"H" input voltage		0.7VDD	—	VDD	V
VIL	"L" input voltage		0	—	0.3VDD	V
IDS	Drain output current (Current per 1 circuit when 8 circuits are coming on simultaneously)	P	Duty Cycle no more than 45%	0	—	200
			Duty Cycle no more than 100%	0	—	135
		FP	Duty Cycle no more than 34%	0	—	200
			Duty Cycle no more than 100%	0	—	120
		KP	Duty Cycle no more than 18%	0	—	200
			Duty Cycle no more than 100%	0	—	95
VIN	Input voltage		0	—	VDD	V
tr, tf	Rise time, Fall time, drain output	VDD = 4.5V	0	—	500	ns
tsu	Setup time before CLK ↑	VDD = 4.5V	20	—	—	ns
th	Hold time, data after CLK ↑	VDD = 4.5V	5	—	—	ns
tw	Pulse duration	VDD = 4.5V	40	—	—	ns
f	Clock frequency	VDD = 4.5V	—	—	20	MHz

ELECTRICAL CHARACTERISTICS (Unless otherwise noted, $V_{DD} = 5V$, $T_a = 25^\circ C$)

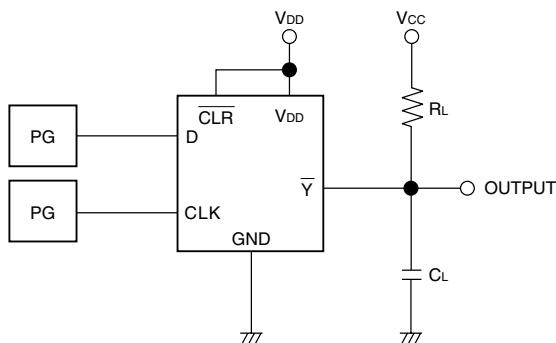
Symbol	Parameter	Test conditions	Limits			Unit
			min	typ	max	
$V_{(BR)DSX}$	Drain-source breakdown voltage	$IDS = 1mA$	40	—	—	V
IDS_X	Drain-source leakage current	$V_{DS} = 40V$	—	0.002	5	μA
I_{IH}	"H" input current	$V_{DD} = 5.5V$, $V_I = 5.5V$	—	0.005	1	μA
I_{IL}	"L" input current	$V_{DD} = 5.5V$, $V_I = 0V$	—	0.005	-1	μA
I_{CC}	Supply current	$V_{DD} = 5.5V$	All outputs off	—	0.005	5
		$V_I = 5.5V$ or $0V$	All outputs on	—	0.005	5
V_{DS}	"L" output voltage	$IDS = 100mA$, $V_{DD} = 4.5V$	—	0.25	0.38	V
		$IDS = 200mA$, $V_{DD} = 4.5V$	—	0.51	0.77	
$R_{DS(on)}$	Drain-source on-state resistance	$IDS = 100mA$, $V_{DD} = 4.5V$	—	2.5	3.8	Ω

SWITCHING CHARACTERISTICS ($V_{DD} = 5V$, $T_a = 25^\circ C$)

Symbol	Parameter	Test conditions	Limits			Unit
			min	typ	max	
t_{TLH}	Low-level to high-level and high-level to low-level output transition time	$CL = 30pF$ (Note 1)	—	10	—	ns
t_{THL}			—	3	—	ns
t_{PLH}			—	35	—	ns
t_{PHL}			—	30	—	ns
$t_{PLH(R)}$			—	35	—	ns

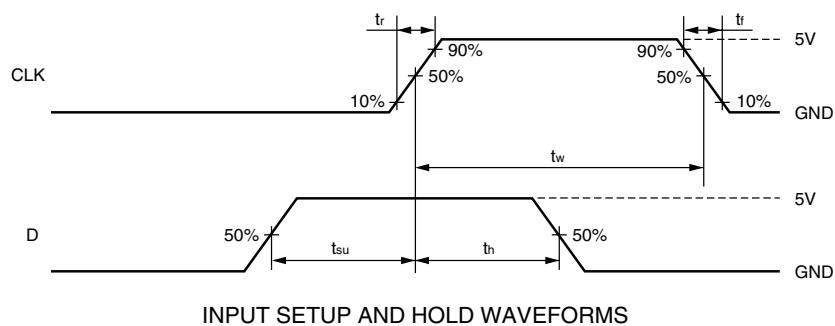
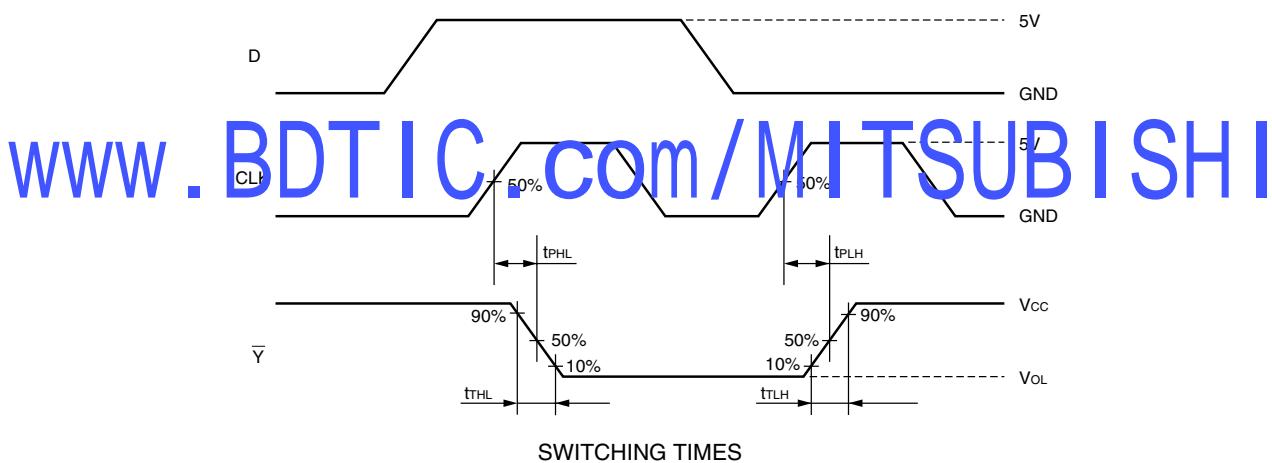
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NOTE 1 TEST CIRCUIT

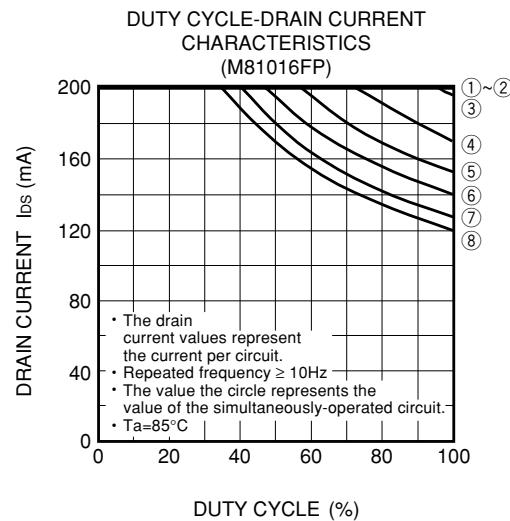
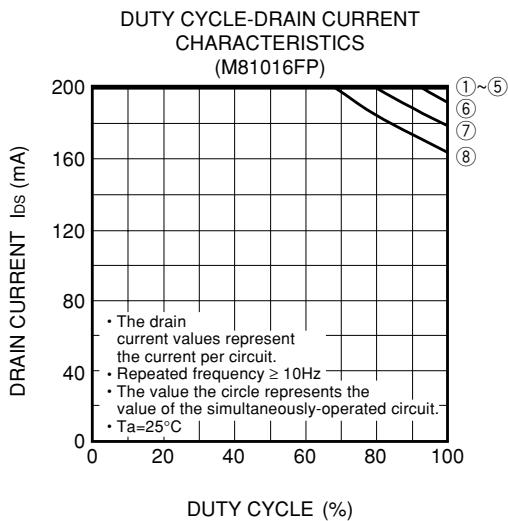
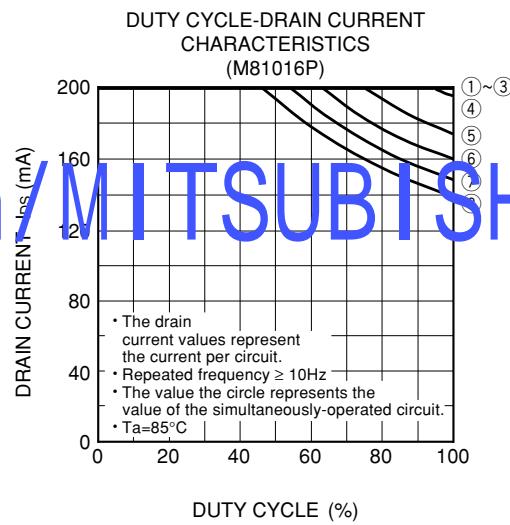
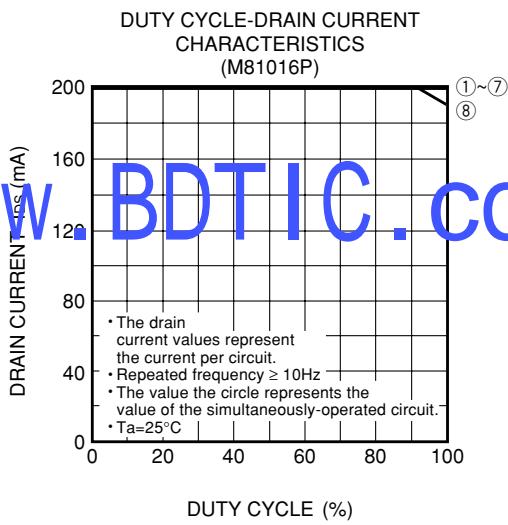
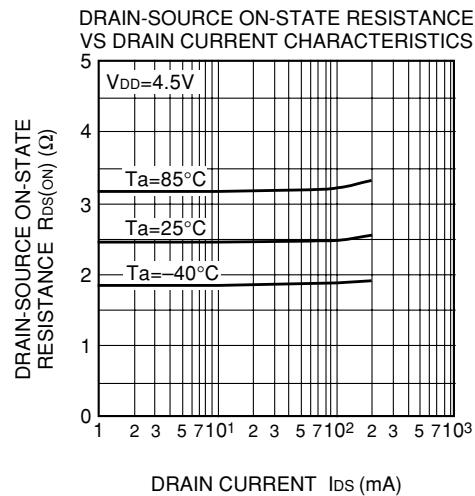
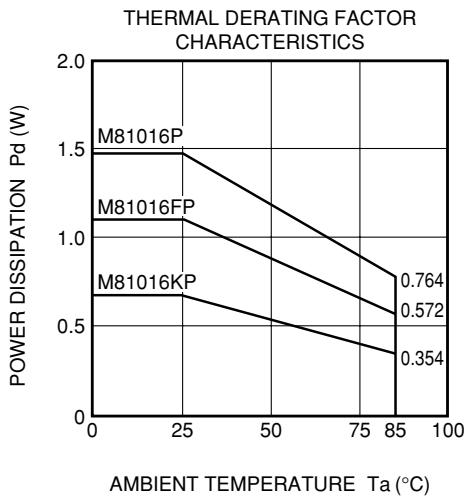


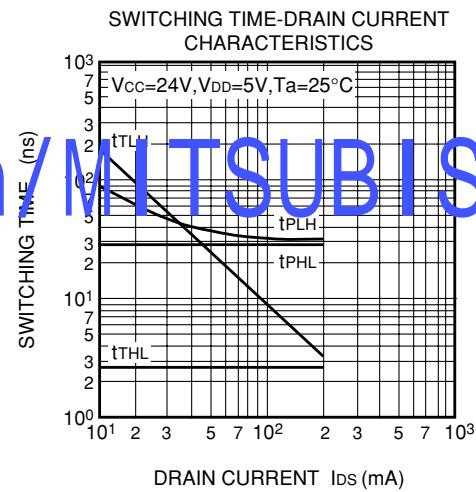
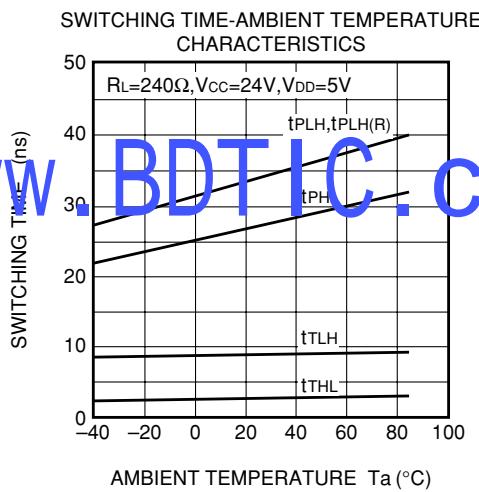
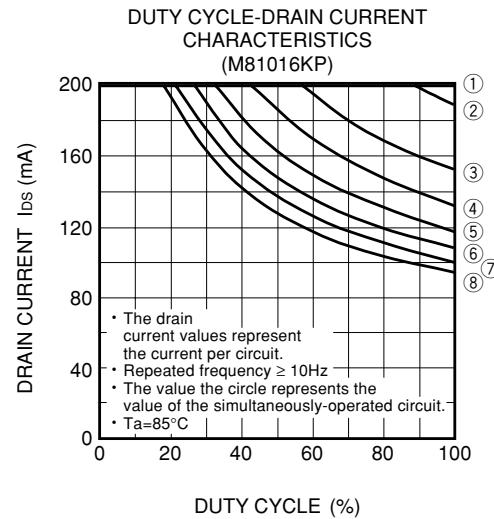
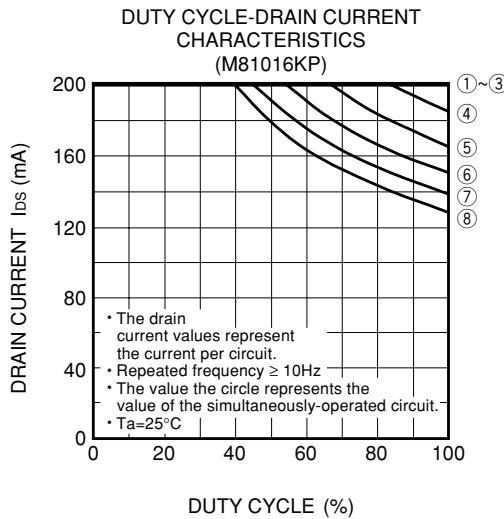
- (1) Pulse generator (PG) characteristics : PRR = 1MHz,
Duty Cycle = 50%, $t_r = 6\text{ns}$, $t_f = 6\text{ns}$, $Z_0 = 50\Omega$, $V_I = 5\text{V}$
(2) Output conditions : $R_L = 240\Omega$, $V_{CC} = 24\text{V}$, $V_{DD} = 5\text{V}$
(3) Electrostatic capacity C_L includes floating capacitance
at connections and input capacitance at probes.

TIMING DIAGRAM



TYPICAL CHARACTERISTICS

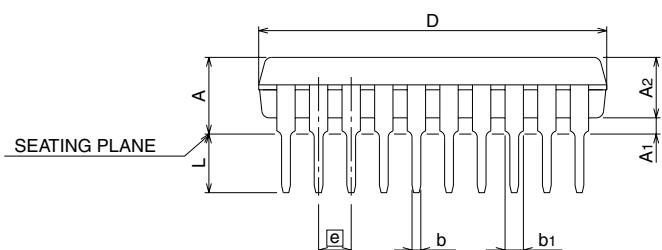
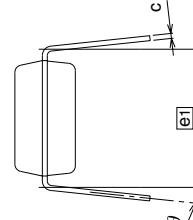
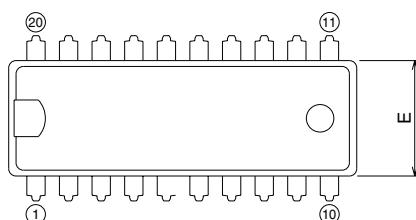




20P4B

Plastic 20pin 300mil SDIP

EIAJ Package Code	JEDEC Code	Weight(g)	Lead Material
SDIP20-P-300-1.78	-	1.0	Alloy 42/Cu Alloy



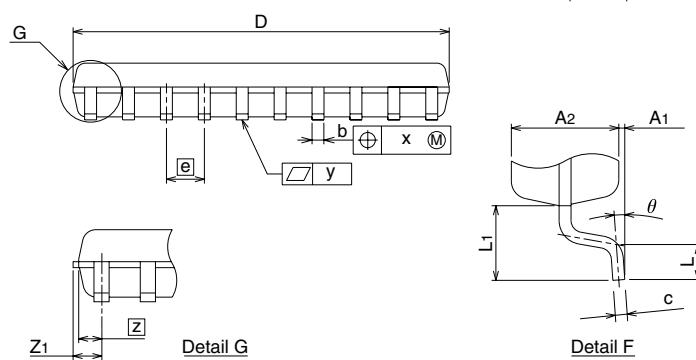
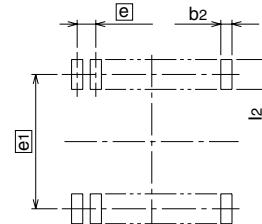
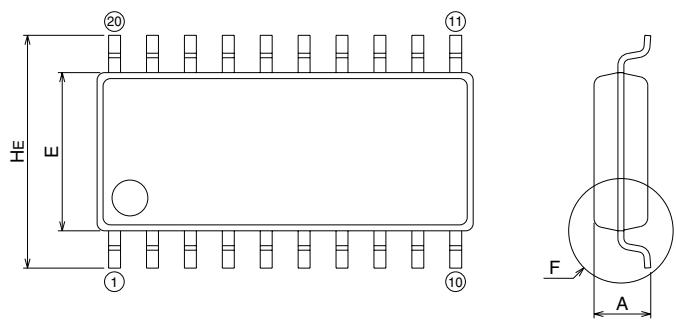
Symbol	Dimension in Millimeters		
	Min	Nom	Max
A	-	-	4.5
A1	0.51	-	-
A2	-	3.3	-
b	0.38	0.48	0.58
b1	0.9	1.0	1.3
c	0.22	0.27	0.34
D	18.8	19.0	19.2
E	6.15	6.3	6.45
e	-	1.778	-
e1	-	7.62	-
i	3.0	-	15°
θ	0°	-	15°

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20P2N-A

Plastic 20pin 300mil SOP

EIAJ Package Code	JEDEC Code	Weight(g)	Lead Material
SOP20-P-300-1.27	-	0.26	Cu Alloy

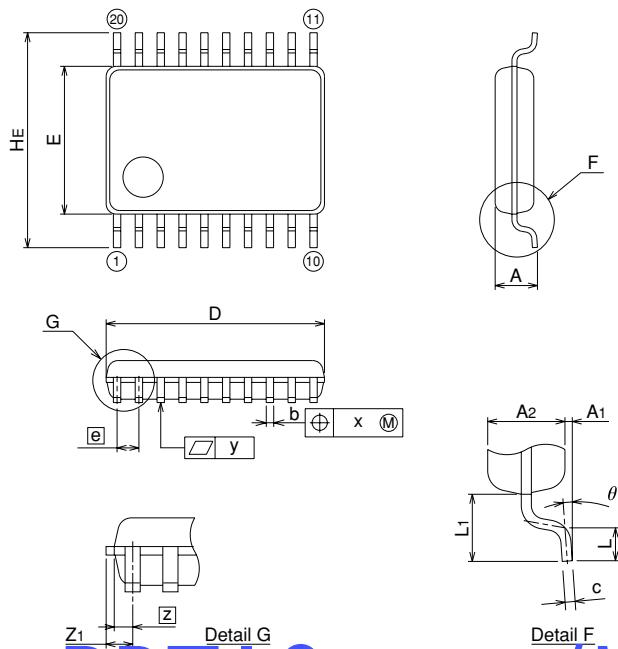
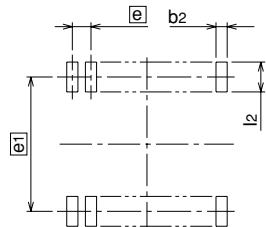


Recommended Mount Pad

Symbol	Dimension in Millimeters		
	Min	Nom	Max
A	-	-	2.1
A1	0	0.1	0.2
A2	-	1.8	-
b	0.35	0.4	0.5
c	0.18	0.2	0.25
D	12.5	12.6	12.7
E	5.2	5.3	5.4
e	-	1.27	-
HE	7.5	7.8	8.1
L	0.4	0.6	0.8
L1	-	1.25	-
Z	-	0.585	-
Z1	-	-	0.735
x	-	-	0.25
y	-	-	0.1
θ	0°	-	8°
b1	-	0.76	-
e1	-	7.62	-
l2	1.27	-	-

20P2E-A

EIAJ Package Code	JEDEC Code	Weight(g)	Lead Material
SSOP20-P-225-0.65	-	0.08	Alloy 42

**Plastic 20pin 225mil SSOP**

Recommended Mount Pad

Symbol	Dimension in Millimeters		
	Min	Nom	Max
A	—	—	1.45
A1	0	0.1	0.2
A2	—	1.15	—
b	0.17	0.22	0.32
c	0.13	0.15	0.2
D	6.4	6.5	6.6
E	4.3	4.4	4.5
[e]	—	0.65	—
HE	6.2	6.4	6.6
L	0.3	0.5	0.7
L1	—	1.0	—
[Z]	—	0.325	—
Z1	—	—	0.475
x	—	—	0.13
y	—	—	0.1
θ	0°	—	10°
b2	—	0.35	—
[e1]	—	5.8	—
l2	1.0	—	—

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